

# R1200 THRU R2000

## HIGH VOLTAGE SILICON RECTIFIERS

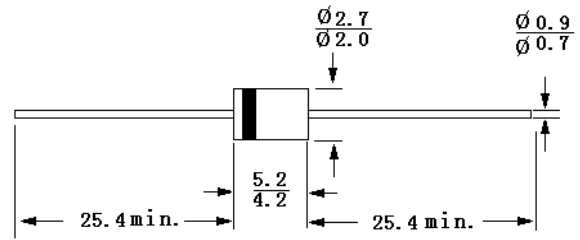
Reverse Voltage – 1200 to 2000 Volts

Forward Current – 0.2 to 0.5 Ampere

DO-41

### Features

- Low cost
- Low leakage
- Low forward voltage drop
- High current capability



### Mechanical Data

Dimensions in mm

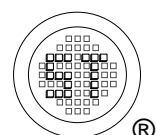
- **Case:** Molded plastic, DO-41
- **Mounting Position:** Any
- **Terminals:** Axial leads, solderable per MIL-STD-202

### Absolute Maximum Ratings and Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz. resistive or inductive load. For capacitive load, derate current by 20%.

		Symbols	R1200	R1500	R1800	R2000	Units
Maximum recurrent peak reverse voltage		$V_{RRM}$	1200	1500	1800	2000	Volts
Maximum RMS voltage		$V_{RMS}$	840	1050	1260	1400	Volts
Maximum DC blocking voltage		$V_{DC}$	1200	1500	1800	2000	Volts
Maximum average forward rectified current at $T_A = 55^\circ\text{C}$		$I_O$	500			200	mAmps
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load(JEDEC method)		$I_{FSM}$	30				Amps
Maximum instantaneous forward voltage at 0.5A/0.2A DC		$V_F$	2			3	Volts
Maximum DC reverse current at rated DC blocking voltage	@ $T_A = 25^\circ\text{C}$	$I_R$	5				$\mu\text{Amps}$
	@ $T_A = 100^\circ\text{C}$		100				
	Maximum full load reverse current average, Full cycle 0.375" (9.5 mm) lead length at $T_L = 75^\circ\text{C}$		30				$\mu\text{Amps}$
Typical junction capacitance (Note )		$C_J$	30				pF
Operating and storage temperature range		$T_J, T_{Stg}$	-55 to +150				$^\circ\text{C}$

Notes: Measured at 1MHz and applied reverse voltage of 4volts.



Dated : 30/03/2005 H

# R1200 THRU R2000

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

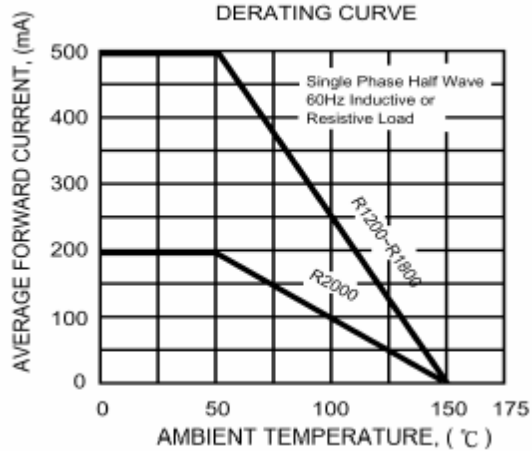


FIG. 2 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

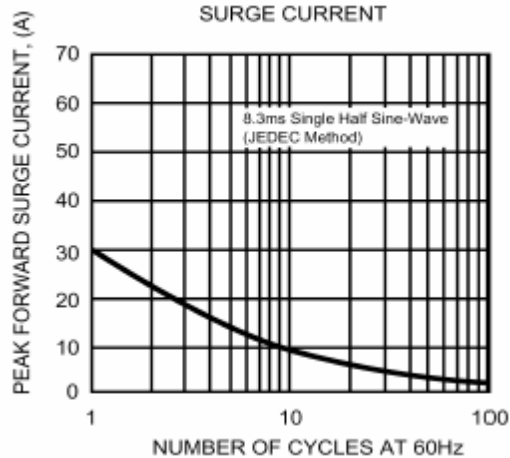


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

